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QUADRUPLE 3-STATE BUFFERS OF HIGH

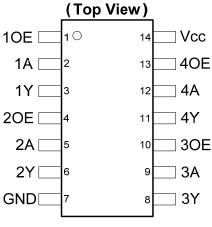
Description

The 74HC126 provides provides four independent buffer gates with 3-state outputs. Each buffer has a separate enable pin that if driven with a low logic level places the corresponding output in the high impedance state. The device is designed for operation with a power supply range of 2.0V to 6.0V.

Features

- Wide Supply Voltage Range from 2.0V to 6.0V
- Sinks or sources 4mA at V_{CC} = 4.5V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



SO-14 / TSSOP-14

Applications

- General Purpose Logic
- · Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

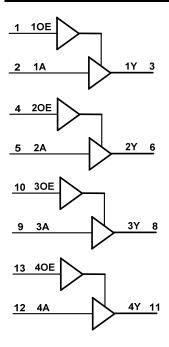
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Pin Descriptions

Pin Number	Pin Name	Function
1	10E	Data Enable Input (active low)
2	1A	Data Input
3	1Y	Data Output
4	20E	Data Enable Input (active low)
5	2A	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	3OE	Data Enable Input (active low)
11	4Y	Data Outp
12	4A	Data Input
13	40E	Data Enable Input (active low)
14	Vcc	Supply Voltage

Logic Diagram



Function Table

Inp	Output	
OE	Α	Y
Н	Н	Н
Н	L	L
L	X	Z



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +7.0	V
Vı	Input Voltage Range (Note 5)	-0.5 to +7.0	V
I _{IK}	Input Clamp Current V _I < -0.5V or Vi > V _{CC} +0.5V	±20	mA
lok	Output Clamp Current $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$	±20	mA
Ιο	Continuous Output Current -0.5V < V _O V _{CC} +0.5V	+/- 25	mA
I _{CC}	Continuous Current Through V _{CC}	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
P _{TOT}	Total Power Dissipation	500	mW

Notes:

Recommended Operating Conditions (Note 6) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage		2.0	6.0	V
VI	Input Voltage		0	V _{CC}	V
Vo	Output Voltage		0	V _{CC}	V
		V _{CC} = 2.0V		625	
Δt/ΔV	Input Transition Rise or Fall Rate	V _{CC} = 4.5V		140	ns/V
		V _{CC} = 6.0V		85	
T _A	Operating Free-Air Temperature		-40	+125	°C

Note: 6. Unused inputs should be held at V_{CC} or ground.

^{4.} Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

^{5.} Input Voltage cannot exceed V_{CC} to the extent the Maximum clamp current is exceeded.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Comple ed	Domenton	Test Conditions		T _A = -40°	C to +85°C	T _A = -40°C to +125°C		Unit	
Symbol	Parameter	rest Conditions	Vcc	Min	Max	Min	Max	Unit	
			2.0V	1.5		1.5			
V_{IH}	High-level Input Voltage		4.5V	3.15		3.15		V	
			6.0V	4.2		4.2			
			2.0V		0.5		0.5		
V_{IL}	Low-level input voltage		4.5V		1.35		1.35	V	
			6.0V		1.8		1.8		
		$I_{OH} = -20 \mu A$	2.0V	1.9		1.9		V	
		$I_{OH} = -20 \mu A$	4.5V	4.4		4.4			
V_{OH}	High-level Output Voltage	I _{OH} = -20μA	6.0V	5.9		5.9			
		$I_{OH} = -4.0 \text{mA}$	4.5V	3.84		3.7			
		I _{OH} = -5.2mA	6.0V	5.34		5.2			
		I _{OL} = 20μA	2.0V		0.1		0.1		
		I _{OL} = 20μA	4.5V		0.1		0.1	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
V_{OL}	Low-level Output Voltage	I _{OL} = 20μA	6.0V		0.1		0.1		
		I _{OL} = 4mA	4.5V		0.33		0.44		
		I _{OL} = 5.2mA	6.0V		0.33		0.44	1	
l _{OZ}	Z State Leakage Current	V _O = 0 to 6.0V	6.0V		± 5.0		± 10	μA	
102	_	V _I = GND or 6.0V	J.0 V		2 0.0		- 10	μ, ,	
lı	Input Current	$V_I = GND \text{ to } 5.5V$	6.0V		± 1		± 1	μΑ	
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	6.0V		20		40	μΑ	

Switching Characteristics

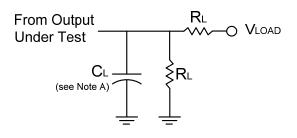
Symbol	Parameter	Test	V		T _A = +25°C	;	-40°C to +85°C	-40°C to +125°C	Unit
Symbol	Parameter	Conditions	V _{CC}	Min	Тур	Max	Max	Max	Ullit
	Deservation	Ciguro 1	2.0V	_	30	100	125	150	
t _{PD}	Propagation Delay A _N to Y _N	Figure 1 $C_L = 50pF$	4.5V	_	11	20	25	30	ns
	Delay An to Th	CL = 50PF	6.0V	_	9	17	21	26	
		Figure 1	2.0V	_	41	125	155	190	
t _{EN}	E <u>na</u> ble Time	Figure 1 $C_L = 50pF$	4.5V	_	15	25	31	38	ns
	OE _N to Y _N	CL - 30pi	6.0V	_	12	21	26	32	
		Figure 1	2.0V	_	41	125	155	190	
t _{DIS}	Disable Time	Figure 1 $C_L = 50pF$	4.5V	_	15	25	31	38	ns
	\overline{OE}_N to Y_N	CL = 50pF	6.0V	_	12	21	26	32	
		Figure 1	2.0V	_	14	60	75	90	
t _t	Transition Time	Figure 1 $C_L = 50pF$	4.5V	_	5	12	15	18	ns
		CL = 50PF	6.0V	_	4	10	13	15	

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter	Test Conditions	V _{CC} = 6V Typ	Unit
C _{pd}	Power Dissipation Capacitance per Gate	f = 1 MHz	22	pF
Cı	Input Capacitance	$V_1 = V_{CC} - \text{or GND}$	4	pF



Parameter Measurement Information



TEST	Condition
t _{PLZ} (see Notes D and E)	Vload
t _{PZL} (see Notes D and F)	Vload

V	Inputs		V	V		В	V Δ
V _{CC}	VI	t_r/t_f	V _M	V _{LOAD}	C _L	KL	VΔ
2.0V to 6.0V	V _{CC}	≤3ns	V _{CC} /2	2 X V _{CC}	15,50 pF	2 ΚΩ	10% of V _{CC}

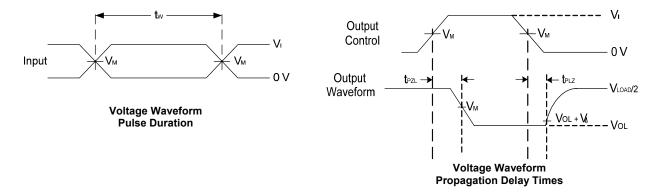


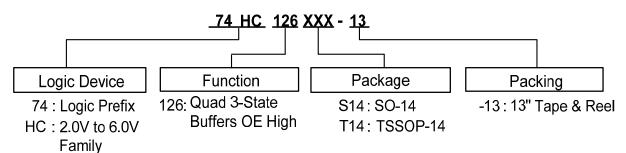
Figure 1 Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 1 MHz
- C. The inputs are measured one at a time with one transition per measurement.
- D. For the 3 state device t_{PLZ} and t_{PZL} are the same as t_{PD}
- E. t_{PZL} is measured at V_{M} .
- D. t_{PLZ} is measured at V_{OL} + V_{Δ}



Ordering Information

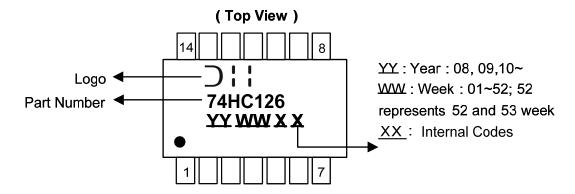


Device

	Device	Backage Code	Dockoning	7" Tape	and Reel
	Device	Package Code	Packaging	Quantity	Part Number Suffix
Green	74HC126S14-13	S14	SO-14	2500/Tape & Reel	-13
Green	74HC126T14-13	T14	TSSOP-14	2500/Tape & Reel	-13

Marking Information

(1) SO-14, TSSOP-14



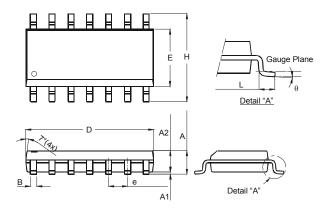
Part Number	Package
74HC126S14	SO-14
74HC126T14	TSSOP-14



Package Outline Dimensions (All dimensions in mm.)

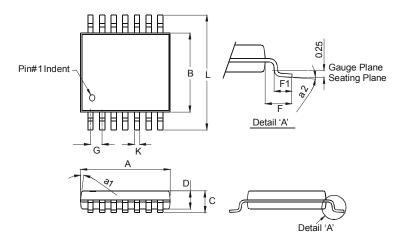
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



SO-14		
Dim	Min	Max
Α	1.47	1.73
A1	0.10	0.25
A2	1.45 Typ	
В	0.33	0.51
D	8.53	8.74
Е	3.80	3.99
е	1.27 Typ	
Н	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Dimensions in mm		

Package Type: TSSOP-14



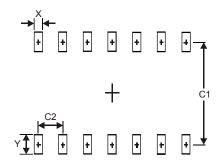
TSSOP-14			
Dim	Min	Max	
a1	7° (4X)		
a2	0°	8°	
Α	4.9	5.10	
В	4.30	4.50	
С		1.2	
D	0.8	1.05	
F	1.00 Typ		
F1	0.45	0.75	
G	0.65 Typ		
K	0.19	0.30	
Ĺ	6.40 Typ		
All Dimensions in mm			



Suggested Pad Layout

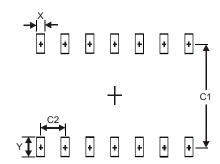
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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